P Package

Quad EIA-485 Line Drivers with Three-State Outputs

The ON Semiconductor MC75172B/174B Quad Line drivers are differential high speed drivers designed to comply with the EIA–485 Standard. Features include three–state outputs, thermal shutdown, and output current limiting in both directions. These devices also comply with EIA–422–A, and CCITT Recommendations V.11 and X.27.

The MC75172B/174B are optimized for balanced multipoint bus transmission at rates in excess of 10 MBPS. The outputs feature wide common mode voltage range, making them suitable for party line applications in noisy environments. The current limit and thermal shutdown features protect the devices from line fault conditions. These devices offer optimum performance when used with the MC75173 and MC75175 line receivers.

Both devices are available in 16-pin plastic DIP and 20-pin wide body surface mount packages.

- Meets EIA-485 Standard for Party Line Operation
- Meets EIA-422-A and CCITT Recommendations V.11 and X.27
- Operating Ambient Temperature: -40°C to +85°C
- High Impedance Outputs
- Common Mode Output Voltage Range: -7 to 12 V
- Positive and Negative Current Limiting
- Transmission Rates in Excess of 10 MBPS
- Thermal Shutdown at 150°C Junction Temperature, (±20°C)
- Single 5.0 V Supply

1A 1

1Y 2

1Z 3

En 4

2Z 5

2Y 6

2A 7

Gnd 8

- Pin Compatible with TI SN75172/4 and NS $\mu A96172/4$

MC75172B

16 V_{CC} 1A 1

1Y 2

NC 3

1Z 4

En 5

2Z 6

NC 7

2Y 8

2A 9

Gnd 10

15 4A

4 4Y

13 4Z

12 En

11 3Z

10 3Y

9 3A

• Interchangeable with MC3487 and AM26LS31 for EIA–422–A Applications

MC75172B MC75174B

QUAD EIA-485 LINE DRIVERS

SEMICONDUCTOR TECHNICAL DATA



P SUFFIX PLASTIC PACKAGE CASE 648

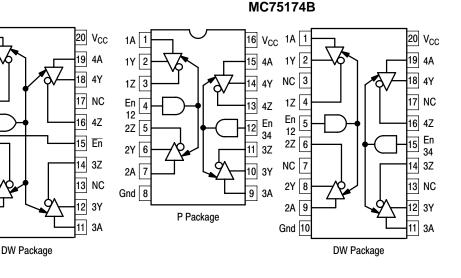
DW SUFFIX PLASTIC PACKAGE CASE 751D (SO–20L)



ORDERING INFORMATION

Device	Operating Temperature Range	Package
MC75172BDW		SO-20L
MC75174BDW	$T_A = -40^\circ$ to +85°C	SO-20L
MC75174BP		Plastic DIP

PIN CONNECTIONS





MAXIMUM RATINGS

Rating	Symbol	Value	Unit
Power Supply Voltage	V _{CC}	-0.5, +7.0	Vdc
Input Voltage (Data, Enable)	V _{in}	+7.0	Vdc
Input Current (Data, Enable)	l _{in}	-24	mA
Applied Output Voltage, when in 3–State Condition $(V_{CC} = 5.0 \text{ V})$	V _{za}	-10, +14	Vdc
Applied Output Voltage, when $V_{CC} = 0 V$	V _{zb}	±14	
Output Current	Ι _Ο	Self-Limiting	_
Storage Temperature	T _{stg}	-65, +150	°C

Devices should not be operated at these limits. The "Recommended Operating Conditions" table provides for actual device operation.

RECOMMENDED OPERATING CONDITIONS

Characteristic	Symbol	Min	Тур	Max	Unit
Power Supply Voltage	V _{CC}	+4.75	+5.0	+5.25	Vdc
Input Voltage (All Inputs)	V _{in}	0	-	V _{CC}	Vdc
Output Voltage in 3–State Condition, or when $V_{CC} = 0 V$	V _{cm}	-7.0	-	+12	Vdc
Output Current (Normal data transmission)	IO	-65	-	+65	mA
Operating Ambient Temperature (see text) EIA–485 EIA–422	T _A	40 0		+85 +85	°C

All limits are not necessarily functional concurrently.

$\textbf{ELECTRICAL CHARACTERISTICS} \ (-40^{\circ}C \leqslant T_{A} \leqslant 85^{\circ}C, \ 4.75 \ V \leqslant V_{CC} \leqslant 5.25 \ V, \ unless \ otherwise \ noted.)$

Characteristic	Symbol	Min	Тур	Max	Unit
Output Voltage					
Single–Ended Voltage					Vdc
$I_{O} = 0$	Vo	0	-	6.0	
High @ I _O = –33 mA	V _{OH}	-	4.0	-	
Low @ I _O = +33 mA	V _{OL}	-	1.6	-	
Differential Voltage					
Open Circuit (I _O = 0)	V _{OD1}	1.5	3.4	6.0	
$R_L = 54 \Omega$ (Figure 1)	IV _{OD2} I	1.5	2.3	5.0	
Change in Differential [*] , $R_{L} = 54 \Omega$ (Figure 1)		-	5.0	200	mVdc
Differential Voltage, $R_L = 100 \Omega$ (Figure 1)	V _{OD2A}	-	2.2	-	Vdc
Change in Differential [*] , $R_L = 100 \Omega$ (Figure 1)		-	5.0	200	mVdc
Differential Voltage, –7.0 V \leq V _{cm} \leq 12 V (Figure 2)	N _{OD3} I	1.5	-	5.0	Vdc
Change in Differential*, –7.0 V \leq V _{cm} \leq 12 V (Figure 2)		-	5.0	200	mVdc
Offset Voltage, $R_L = 54 \Omega$ (Figure 1)	Vos	-	2.9	-	Vdc
Change in Offset [*] , $R_L = 54 \Omega$ (Figure 1)	ΔV _{OS}	-	5.0	200	mVdc
Output Current (Each Output)					
Power Off Leakage, $V_{CC} = 0, -7.0 \text{ V} \le V_O \le 12 \text{ V}$	I _{O(off)}	-50	0	+50	μA
Leakage in 3–State Mode, –7.0 V \leq V _O \leq 12 V	I _{OZ}	-50	0	+50	·
Short Circuit Current to Ground	I _{OSR}	-150	_	+150	mA
Short Circuit Current, –7.0 V \leq V _O \leq 12 V	los	-250	-	+250	

 $^*V_{in}$ switched from 0.8 to 2.0 V. Typical values determined at 25°C ambient and 5.0 V supply.

ELECTRICAL CHARACTERISTICS (-40°C \leq T_A \leq 85°C, 4.75 V \leq V_{CC} \leq 5.25 V, unless otherwise noted.)

Characteristics	Symbol	Min	Тур	Max	Unit
Inputs					Vdc
Low Level Voltage (Pins 4 & 12, MC75174B only)	V _{IL(A)}	0	-	0.7	
Low Level Voltage (All Other Pins)	V _{IL(B)}	0	-	0.8	
High Level Voltage (All Inputs)	VIH	2.0	-	V _{CC}	
Current @ V _{in} = 2.7 V (All Inputs)	IIH	-	0.2	20	μA
Current @ V _{in} = 0.5 V (All Inputs)	IIL	-100	-15	-	
Clamp Voltage (All Inputs, I _{in} = -18 mA)	V _{IK}	-1.5	-	-	Vdc
Thermal Shutdown Junction Temperature	T _{jts}	-	+150	-	°C
Power Supply Current (Outputs Open, V _{CC} = 5.25 V)	I _{CC}				mA
Outputs Enable		-	60	70	
Outputs Disabled		-	30	40	

TIMING CHARACTERISTICS (T_A = 25° C, V_{CC} = 5.0 V)

Characteristics	Symbol	Min	Тур	Max	Unit
Propagation Delay – Input to Single–ended Output (Figure 3) Output Low–to–High Output High–to–Low	t _{PLH} t _{PHL}		23 18	30 30	ns
Propagation Delay – Input to Differential Output (Figure 4) Input Low–to–High Input High–to–Low	t _{PLH(D)} t _{PHL(D)}		15 17	25 25	ns
Differential Output Transition Time (Figure 4)	t _{dr} , t _{df}	-	19	25	ns
Skew Timing $ t_{PLHD} - t_{PHLD} $ for Each Driver Max – Min t _{PLHD} Within a Package Max – Min t _{PHLD} Within a Package	tsk1 tsk2 tsk3		0.2 1.5 1.5		ns
Enable Timing Single–ended Outputs (Figure 5) Enable to Active High Output Enable to Active Low Output Active High to Disable (using Enable) Active Low to Disable (using Enable) Enable to Active High Output (MC75172B only) Enable to Active Low Output (MC75172B only) Active High to Disable (using Enable, MC75172B only) Active Low to Disable (using Enable, MC75172B only)	^t PZH(E) tPZL(E) tPHZ(E) tPLZ(E) tPZH(E) tPZL(E) tPHZ(E) tPLZ(E)	- - - - - -	48 20 35 30 58 28 38 38 36	60 30 45 50 70 35 50 50	ns
Differential Outputs (Figure 6) Enable to Active Output Enable to Active Output (MC75172B only) Enable to 3–State Output Enable to 3–State Output (MC75172B only)	^t PZD(E) ^t PZD(E) ^t PDZ(E) ^t PDZ(E)	- - - -	47 56 32 40	- - - -	ns

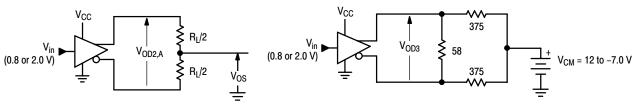


Figure 1. V_{DD} Measurement

Figure 2. Common Mode Test

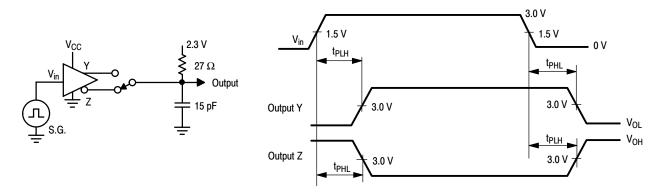
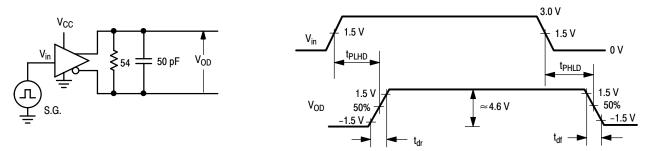


Figure 3. Propagation Delay, Single–Ended Outputs

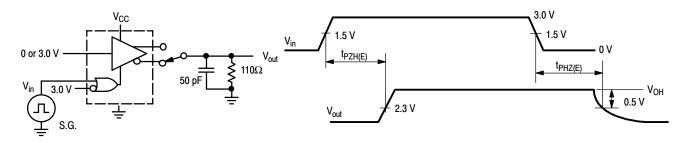


NOTES: 1. S.G. set to: f $\,\leq\,$ 1.0 MHz; duty cycle = 50%; t_{\rm f}, t_{\rm f}, \,\leq\, 5.0 ns.

2. $t_{SK1} = |t_{PLHD} - t_{PHLD}|$ for each driver.

3. t_{SK2} computed by subtracting the shortest t_{PLHD} from the longest t_{PLHD} of the 4 drivers within a package. 4. t_{SK3} computed by subtracting the shortest t_{PHLD} from the longest t_{PHLD} of the 4 drivers within a package.

Figure 4. Propagation Delay, Differential Outputs



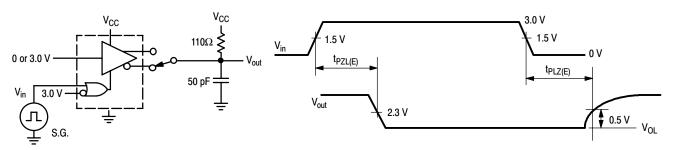
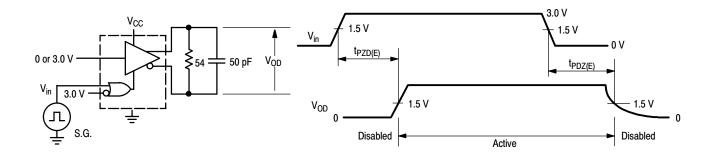
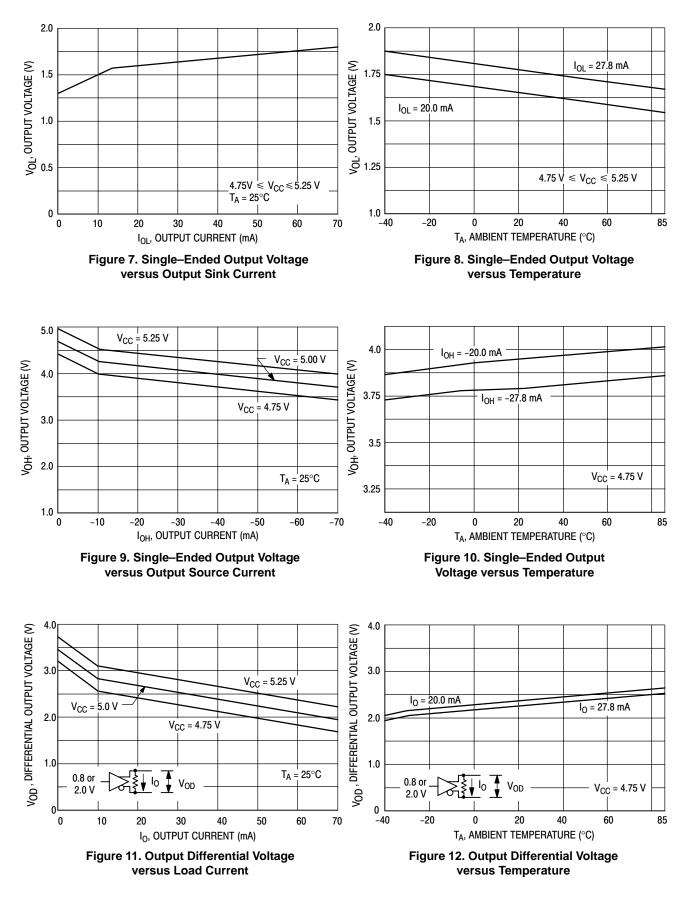


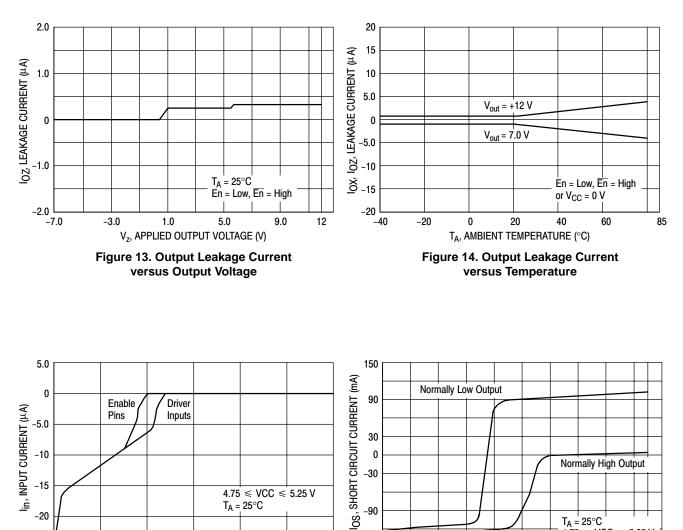
Figure 5. Enable Timing, Single–Ended Outputs



NOTES: 1. S.G. set to: $f \le 1.0 \text{ MHz}$; duty cycle = 50%; t_f , t_f , $\le 5.0 \text{ ns.}$ 2. V_{in} is inverted for Enable measurements.

Figure 6. Enable Timing, Differential Outputs





-90

-150

-7.0

-3.0

1.0

Vz, APPLIED OUTPUT VOLTAGE (V)

Figure 16. Short Circuit Current

versus Common Mode Voltage

5.0

5.5

 $T_{A} = 25^{\circ}C$ 4.75 \leq VCC \leq 5.25 V

9.0

12

4.75 ≤ VCC ≤ 5.25 V

4.5

T_A = 25°C

3.5

-15

-20

-25

-0.5

0.5

1.5

2.5

Vin, INPUT VOLTAGE (V)

Figure 15. Input Current

versus Input Voltage

APPLICATIONS INFORMATION

Description

The MC75172B and MC75174B are differential line drivers designed to comply with EIA–485 Standard (April 1983) for use in balanced digital multipoint systems containing multiple drivers. The drivers also comply with EIA–422–A and CCITT Recommendations V.11 and X.27. The drivers meet the EIA–485 requirement for protection from damage in the event that two or more drivers attempt to transmit data simultaneously on the same cable. Data rates in excess of 10 MBPS are possible, depending on the cable length and cable characteristics. A single power supply, 5.0 V, \pm 5%, is required at a nominal current of 60 mA, plus load currents.

Outputs

Each output (when active) will be a low or a high voltage, which depends on the input state and the load current (see Table 1, 2 and Figures 7 to 10). The graphs apply to each driver, regardless of how many other drivers within the package are supplying load current.

	Enables		Out	puts
Data Input	EN	EN	Y	Z
Н	Н	Х	Н	L
L	н	Х	L	н
Н	Х	L	н	L
L	Х	L	L	Н
Х	L	н	Z	Z

Table 1. MC75172B Truth Table

Table 2. MC75174B Truth Table

		Out	puts
Data Input	Enable	Y	Z
Н	Н	Н	L
L	Н	L	Н
Х	L	Z	Z

H = Logic high, L = Logic low, X = Irrelevant, Z = High impedance

The two outputs of a driver are always complementary. A "high" output can only source current out, while a "low" output can only sink current (except for short circuit current – see Figure 16).

The outputs will be in the high impedance mode when:

- a) the Enable inputs are set according to Table 1 or 2;
- b) V_{CC} is less than 1.5 V;
- c) the junction temperature exceeds the trip point of the thermal shutdown circuit (see below). When in this condition, the output's source and sink capability are shut off, and only leakage currents will flow (see Figures 13, 14). Disabled outputs may be taken to any voltage between -7.0 V and 12 V without damage.

The drivers are protected from short circuits by two methods:

- a) Current limiting is provided at each output, in both the source and sink direction, for shorts to any voltage within the range of 12V to -7.0V, with respect to circuit ground (see Figure 16). The short circuit current will flow until the fault is removed, or until the thermal shutdown circuit activates (see below). The current limiting circuit has a negative temperature coefficient and requires no resetting upon removal of the fault condition.
- b) A thermal shutdown circuit disables the outputs when the junction temperature reaches 150° C, $\pm 20^{\circ}$ C. The thermal shutdown circuit has a hysteresis of $\approx 12^{\circ}$ C to prevent oscillations. When this circuit activates, the output stage of each driver is put into the high impedance mode, thereby shutting off the output currents. The remainder of the internal circuitry remains biased. The outputs will become active once again as the IC cools down.

Driver Inputs

The driver inputs determine the state of the outputs in accordance with Tables 1 and 2. The driver inputs have a nominal threshold of 1.2 V, and their voltage must be kept within the range of 0 V to V_{CC} for proper operation. If the voltage is taken more than 0.5 V below ground, excessive currents will flow, and proper operation of the drivers will be affected. An open pin is equivalent to a logic high, but good design practices dictate that inputs should never be left open. The characteristics of the driver inputs are shown in Figure 15. This graph is not affected by the state of the Enable pins.

Enable Logic

Each driver's outputs are active when the Enable inputs (Pins 4 and 12) are true according to Tables 1 and 2.

The Enable inputs have a nominal threshold of 1.2 V and their voltage must be kept within the range of 0 V to V_{CC} for proper operation. If the voltage is taken more than 0.5 V below ground, excessive currents will flow, and proper operation of the drivers will be affected. An open pin is equivalent to a logic high, but good design practices dictate that inputs should never be left open. The Enable input characteristics are shown in Figure 15.

Operating Temperature Range

The minimum ambient operating temperature is listed as -40° C to meet EIA-485 specifications, and 0°C to meet EIA-422-A specifications. The higher V_{OD} required by EIA-422-A is the reason for the narrower temperature range.

The maximum ambient operating temperature (applicable to both EIA–485 and EIA–422–A) is listed as 85°C. However, a lower ambient may be required depending on system use (i.e. specifically how many drivers within a package are used) and at what current levels they are operating. The maximum power which may be dissipated within the package is determined by:

$$PD_{max} = \frac{T_{Jmax} - T_{A}}{R_{\theta JA}}$$

where:

 $R_{\theta JA}$ = package thermal resistance (typical 70°C/W for the DIP package, 85°C/W for SOIC package); T_{Jmax} = max. operating junction temperature, and

 T_A = ambient temperature.

Since the thermal shutdown feature has a trip point of 150° C, $\pm 20^{\circ}$ C, T_{Jmax} is selected to be 130° C. The power dissipated within the package is calculated from:

PD	$= \{ [(V_{CC} - V_{OH}) \bullet I_{OH}] + V_{OL} \bullet I_{OL}) \} \text{ each}$
	driver $+ (V_{CC} \bullet I_{CC})$
where:	V_{CC} = the supply voltage;
	V _{OH} , V _{OL} are measured or estimated from
	Figures 7 to 10;
	I_{CC} = the quiescent power supply current
	(typical 60 mA).

As indicated in the equation, the first term (in brackets) must be calculated and summed for each of the four drivers, while the last term is common to the entire package.

Example 1: $T_A = 25^{\circ}C$, $I_{OL} = I_{OH} = 55$ mA for each driver, $V_{CC} = 5.0$ V, DIP package. How many drivers per package can be used?

Maximum allowable power dissipation is:

$$PD_{max} = \frac{130^{\circ}C - 25^{\circ}C}{70^{\circ}C/W} = 1.5 W$$

Since the power supply current of 60 mA dissipates 300 mW, that leaves 1.2 W (1.5 W – 0.3 W) for the drivers. From Figures 7 and 9, $V_{OL} \approx 1.75$ V, and $V_{OH} \approx 3.85$ V. The power dissipated in each driver is:

 $\{(5.0 - 3.85) \bullet 0.055\} + (1.75 \bullet 0.055) = 160$ mW. Since each driver dissipates 160 mW, the four drivers per package could be used in this application.

Example 2: $T_A = 85^{\circ}C$, $I_{OL} = 27.8 \text{ mA}$, $I_{OH} = 20 \text{ mA}$ for each driver, $V_{CC} = 5.0 \text{ V}$, SOIC package. How many drivers per package can be used?

Maximum allowable power dissipation is:

$$PD_{max} = \frac{130^{\circ}C - 85^{\circ}C}{85^{\circ}C/W} = 0.53 W$$

Since the power supply current of 60 mA dissipates 300 mW, that leaves 230 mW (530 mW - 300 mW) for the

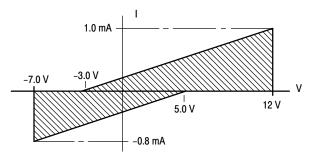
drivers. From Figures 8 and 10 (adjusted for $V_{CC} = 5.0$ V), $V_{OL} \approx 1.38$ V, and $V_{OH} \approx 4.27$ V. The power dissipated in each driver is:

 $\{(5.0 - 4.27) \bullet 0.020\} + (1.38 \bullet 0.0278) = 53 \text{ mW}$

Since each driver dissipates 53 mW, the use of all four drivers in a package would be marginal. Options include reducing the load current, reducing the ambient temperature, and/or providing a heat sink.

System Requirements

EIA–485 requires each driver to be capable of transmitting data differentially to at least 32 unit loads, plus an equivalent DC termination resistance of 60Ω , over a common mode voltage of -7.0 to 12 V. A unit load (U.L.), as defined by EIA–485, is shown in Figure 17.



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Figure 17. Unit Load Definition

A load current within the shaded regions represents an impedance of less than one U.L., while a load current of a magnitude outside the shaded area is greater than one U.L. A system's total load is the sum of the unit load equivalents of each receiver's input current, and each disabled driver's output leakage current. The 60Ω termination resistance mentioned above allows for two 120Ω terminating resistors.

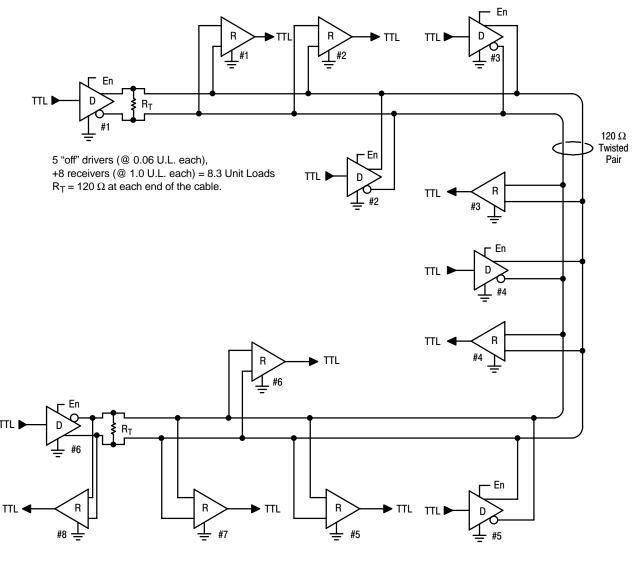
Using the EIA–485 requirements (worst case limits), and the graphs of Figures 7 and 9, it can be determined that the maximum current an MC75172B or MC75174B driver will source or sink is ≈ 65 mA.

System Example

An example of a typical EIA–485 system is shown in Figure 18. In this example, it is assumed each receiver's input characteristics correspond to 1.0 U.L. as defined in Figure 17. Each "off" driver, with a maximum leakage of $\pm 50 \,\mu\text{A}$ over the common mode range, presents a load of $\approx 0.06 \,\text{U.L}$. The total load for the active driver is therefore 8.3 unit loads, plus the parallel combination of the two terminating resistors (60Ω). It is up to the system software to control the driver Enable pins to ensure that only one driver is active at any time.

Termination Resistors

Transmission line theory states that, in order to preserve the shape and integrity of a waveform traveling along a cable, the cable must be terminated in an impedance equal to its characteristic impedance. In a system such as that depicted in Figure 18, in which data can travel in both directions, both physical ends of the cable must be terminated. Stubs, leading to each receiver and driver, should be as short as possible. Leaving off the terminations will generally result in reflections which can have amplitudes of several volts above V_{CC} or below ground. These overshoots and undershoots can disrupt the driver and/or receiver operation, create false data, and in some cases damage components on the bus.



NOTES: 1. Terminating resistors RT must be located at the physical ends of the cable.

2. Stubs should be as short as possible.

Circuit ground of all drivers and receivers must be connected via a dedicated wire within the cable.
 Do not roly on charging ground or power line ground.

Do not rely on chassis ground or power line ground.

Figure 18. Typical EIA-485 System

Comparing System Requirements

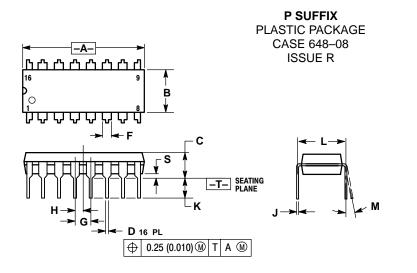
Characteristic	Symbol	EIA-485	EIA-422-A	V.11 and X.27
GENERATOR (DRIVER)	1			
Output Impedance (Note 1)	Z _{out}	Not Specified	<100 Ω	50 10 100 Ω
Open Circuit Voltage Differential Single–Ended	V _{OCD} V _{OCS}	1.5 to 6.0 V <6.0 V	≤6.0 V ≤6.0 V	≤6.0 V, w/3.9 kΩ, Load ≤6.0 V, w/3.9 kΩ, Load
Loaded Differential Voltage	V _{OD}	1.5 to 5.0 V, w/54 Ω load	\geq 2.0 V or \geq 0.5 V _{OCD} , w/100 Ω load	\geq 2.0 V or \geq 0.5 V _{OCD} , w/100 Ω load
Differential Voltage Balance	ΔV_{OD}	<200 mV	≤400 mV	<400 mV
Output Common Mode Range	V _{CM}	-7.0 to +12 V	Not Specified	Not Specified
Offset Voltage	V _{OS}	$-1.0 < V_{OS} < 3.0 V$	≤3.0 V	≤3.0 V
Offset Voltage Balance	ΔV_{OS}	<200 mV	≤400 mV	<400 mV
Short Circuit Current	I _{OS}	≤ 250 mA for -7.0 to 12 V	≤150 mA to ground	≤ 150 mA to ground
Leakage Current ($V_{CC} = 0$)	I _{OLK}	Not Specified	≤100 μA to –0.25 V thru 6.0 V	\leqslant 100 μA to \pm 0.25 V
Output Rise/Fall Time (Note 2)	t _r , t _f	\leq 0.3 T _B , w/54 Ω /1150 pF load	\leq 0.1 T _B or \leq 20 ns, w/100 Ω load	$ \leqslant 0.1 \ T_B \ \text{or} \ \leqslant \ 20 \ \text{ns}, \\ \text{w/100} \ \Omega \ \text{load} $
RECEIVER	1			
Input Sensitivity	V _{th}	± 200 mV	\pm 200 mV	± 300 mV
Input Bias Voltage	V _{bias}	≤3.0 V	≤3.0 V	≤3.0 V
Input Common Mode Range	V _{cm}	-7.0 to 12 V	-7.0 to 7.0 V	-7.0 to 7.0 V
Dynamic Input Impedance	R _{in}	Spec number of U.L.	≥4 kΩ	≥4 kΩ

NOTES: 1. Compliance with V.11 and X.27 (Blue book) output impedance requires external resistors in series with the outputs of the MC75172B and MC75174B. 2. T_B = Bit time.

Additional Information

Copies of the EIA Recommendations (EIA–485 and EIA–422–A) can be obtained from the Electronics Industries Association, Washington, D.C. (202–457–4966). Copies of the CCITT Recommendations (V.11 and X.27) can be obtained from the United States Department of Commerce, Springfield, VA (703–487–4600).

OUTLINE DIMENSIONS

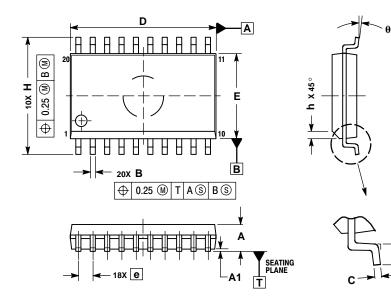


NOTES: 1. DIMENSIONING AND TOLERANCING PER ANSI Y14.5M, 1982. 2. CONTROLLING DIMENSION: INCH. 3. DIMENSION L TO CENTER OF LEADS WHEN FORMED PARALLEL 4. DIMENSION B DOES NOT INCLUDE MOLD FLASH. 5. ROUNDED CORNERS OPTIONAL.

	INCHES		MILLIN	IETERS
DIM	MIN	MAX	MIN	MAX
Α	0.740	0.770	18.80	19.55
В	0.250	0.270	6.35	6.85
С	0.145	0.175	3.69	4.44
D	0.015	0.021	0.39	0.53
F	0.040	0.70	1.02	1.77
G	0.100	BSC	2.54 BSC	
Н	0.050	BSC	1.27 BSC	
J	0.008	0.015	0.21	0.38
K	0.110	0.130	2.80	3.30
L	0.295	0.305	7.50	7.74
М	0°	10 °	0 °	10 °
S	0.020	0.040	0.51	1.01

OUTLINE DIMENSIONS





- NOTES: 1. DIMENSIONS ARE IN MILLIMETERS. 2. INTERPRET DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994. 3. DIMENSIONS D AND E DO NOT INCLUDE MOLD DEDITE ISION
- DIMENSIONS J AND E DO NOT INCLUDE MOLD PROTRUSION.
 MAXIMUM MOLD PROTRUSION 0.15 PER SIDE.
 DIMENSION B DOES NOT INCLUDE DAMBAR PROTRUSION. ALLOWABLE PROTRUSION SHALL BE 0.13 TOTAL IN EXCESS OF B DIMENSION AT MAXIMUM MATERIAL CONDITION.

	MILLIMETERS			
DIM	MIN MAX			
Α	2.35	2.65		
A1	0.10	0.25		
В	0.35	0.49		
C	0.23	0.32		
D	12.65	12.95		
Е	7.40	7.60		
е	1.27	BSC		
H	10.05	10.55		
h	0.25	0.75		
L	0.50	0.90		
θ	0 °	7 °		

<u>Notes</u>

<u>Notes</u>

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